2SA1470/2SC3747



60V/7A High-Speed Switching Applications

Package Dimensions

unit:mm

Applications

- · Inductance, lamp drivers.
- · Inveters, conveters (strobes, flashes, FLT lighting circiuts).
- · Power amplifiers (high-power car stereos, motor control).
- · High-speed switching (switching regulators, drivers).

Features

- · Low saturation votlage.
- \cdot Excellent dependence of h_{FE} on current.
- · Fast switching time.
- · Micaless package facilitating mounting.

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Specifications

Absolute Maximum Ratings at Ta = 25°C

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JEDEC: TO-220ML

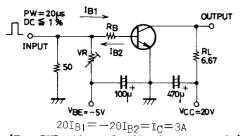
1 : Emitter 2 : Collector 3 : Base

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V _{CBO}		(-)80	V
Collector-to-Emitter Voltage	VCEO		(-)60	V
Emitter-to-Base Voltage	V _{EBO}		(–)5	V
Collector Current	IC		(-)7	Α
Collector Current (Pulse)	I _{CP}		(-)10	Α
Collector Dissipation	PC		2	W
		Tc=25°C	25	W
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

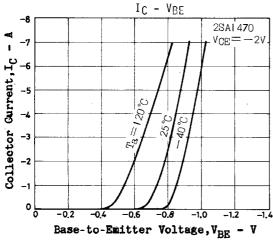
Electrical Characteristics at Ta = 25°C

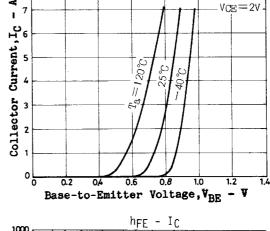
Parameter	Symbol	Conditions	Ratings			Unit
Falametei			min	typ	max	Offic
Collector Cutoff Current	ICBO	V _{CB} =(-)40V, I _E =0			(-)0.1	mA
Emitter Cutoff Current	I _{EBO}	V _{EB} =(-)4V, I _C =0			(-)0.1	mA
DC Current Gain	hFE	V _{CE} =(-)2V, I _C =(-)1A	70*		280*	
Gain-Bandwidth Product	fT	V _{CE} =(-)5V, I _C =(-)1A		100		MHz
Collector-to-Emitter Saturation Voltage	V _{CE(sat)}	I _C =(-)3.5A, I _B =(-)0.175A			(-)0.4	V
Collector-to-Base Breakdown Voltage	V _(BR) CBO	I _C =(-)1mA, I _E =0	(–)80			V
Collector-to-Emitter Breakdown Voltage	V _(BR) CEO	I _C =(-)1mA, R _{BE} =∞	(–)60			V
Emitter-to-Base Breakdown Votage	V(BR)EBO	I _E =(-)1mA, I _C =0	(–)5			V
Turn-ON Time	ton	See specified Test Circuit		0.1		μs
Storage Time	t _{stg}	See specified Test Circuit		0.5		μs
Fall Time	t _f	See specified Test Circuit		0.1		μs

Switching Time Test Circuit



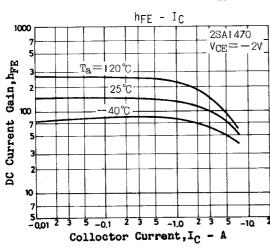
(For PNP, the polarity is reversed.) Unit (resistance: Ω , capacitance: F)

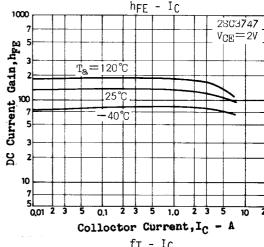


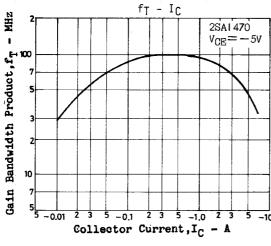


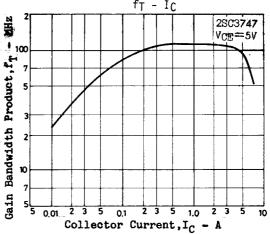
Ic - VBE

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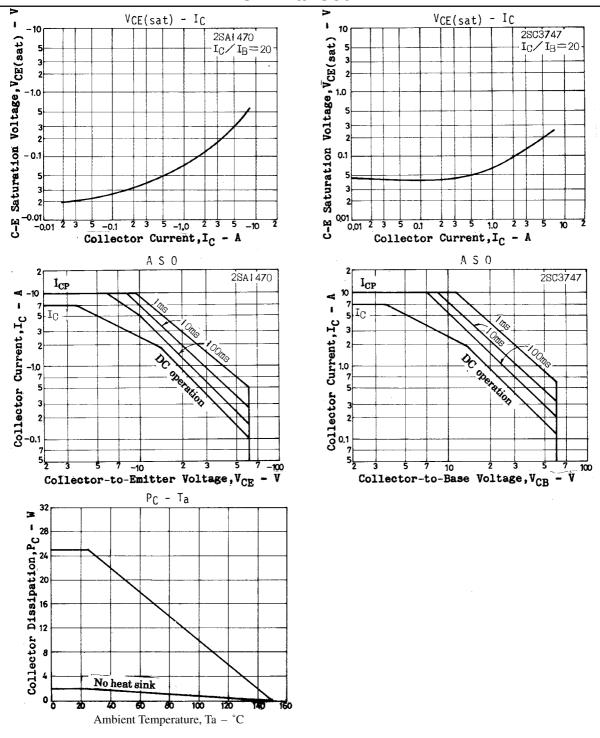








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